Unearthing the foundational role of anharmonicity in heat transport in glasses

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The time-honored Allen-Feldman theory of heat transport in glasses is generally assumed to predict a finite value for the thermal conductivity, even if it neglects the anharmonic broadening of vibrational normal modes. We demonstrate that the harmonic approximation predicts that the bulk lattice thermal conductivity of harmonic solids inevitably diverges at any temperature, irrespective of configurational disorder, and that its ability to represent the heat-transport properties observed experimentally in most glasses is implicitly due to finite-size effects. Our theoretical analysis is thoroughly benchmarked against careful numerical simulations. Our findings thus reveal that a proper account of anharmonic effects is indispensable to predict a finite value for the bulk thermal conductivity in any solid material, be it crystalline or glassy.

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I. INTRODUCTION

In a series of highly influential papers spanning the 1990s [1–5], Allen and Feldman (AF) laid the groundwork for a harmonic theory of heat transport in glasses, which is still considered a landmark in the field. In a nutshell, the AF theory stipulates that disorder alone is able to reduce the heat conductivity from the infinite value it would have in a harmonic crystal to the finite value observed in a glass, without resorting to any anharmonic effects [1,3,6].

This claim notwithstanding, it was immediately realized that harmonic perturbations fulfilling Rayleigh's law introduce an infrared singularity, which inevitably affects any harmonic theory of heat transport in glasses [3], resulting in a divergent bulk thermal conductivity at all temperatures [3,5,7,8]. Although this observation alone would suffice to discredit the entire model, the impact of such singularity on the overall consistency of the AF theory and on the validity of the computations based on it has long been overlooked. On the theoretical side, it was proposed that the same quantumtunneling effects alleged to determine the low-temperature plateau in the conductivity-temperature curve [3,9–14] could also regularize the infrared singularity at high temperatures [2]. Even admitting that quantum effects could survive at hundreds of kelvins, this approach has hardly been pursued in the literature on numerical applications of the AF theory, where the singularity is customarily regularized without relying on any such tunneling effects. Instead, it is not always realized that regularization takes advantage of the finite size of any glass model used in practice, which naturally introduces a low-frequency cutoff, $\omega_{\min} \sim \frac{2\pi c}{L}$, with c being the sound velocity and L the linear size of the system. In addition, the discretization of the spectrum resulting from this finite size requires an *ad hoc* broadening of the vibrational lines to be dealt with, thus inadvertently enhancing the regularization and further concealing the low-lying singularity.

In this paper, we delve into the impact of the infrared singularity in the harmonic theory of heat conduction, demonstrating that a proper account of perturbative anharmonic effects regularizes the bulk limit of the thermal conductivity of amorphous solids at any finite temperature, without the need to rely on tailored quantum-tunneling effects or any arbitrary cutoff.

Surprisingly, we realize that the divergent contribution of frequencies below the infrared cutoff becomes relatively small for most common glasses when anharmonic effects are properly accounted for. Furthermore, we observe that the smearing procedure necessary for conducting AF calculations on finite models acts as an effective boundary-scattering contribution, capable of additional artificial regularization of the thermal conductivity. Our results thus shed light onto the "unreasonable" effectiveness that the AF theory has demonstrated over three decades, recasting it into a size effect resulting from the improper use of finite simulation cells, leading to the neglect of an infinite contribution that, when correctly calculated, is actually relatively small—with notable exceptions, as detailed below.

These findings highlight the intricate interplay between boundary and finite-size effects, on one side, and theoretical predictions, on the other, thus emphasizing the nuanced nature of the AF theory's success. Unearthing the reasons for this success provides solid ground for advancing the theory and numerical simulation of heat transport in glassy materials.

The structure of the article is the following. First, we briefly review the AF theory and its natural extension to account for perturbative anharmonic effects, namely, the quasiharmonic Green-Kubo (QHGK) method [15]. In both approaches, the contribution of low-frequency modes to the heat conductivity can be described by a Debye model whose parameters can be estimated from the vibrational dynamical structure factor (VDSF). Then, using the Debye model, we show that the

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AF prediction for the bulk thermal conductivity diverges at any temperature. This is both theoretically motivated and numerically demonstrated by an accurate finite-size scaling analysis of the thermal conductivity and VDSF of three paradigmatic glasses, amorphous silicon, silica, and silicon carbide. We then examine how this divergence is cured by either boundary scattering or anharmonic effects and discuss the relevance of our findings to experiments performed on thin films. Finally, we present our conclusions.

II. THEORY

A. AF and QHGK models

The AF expression for the heat conductivity of a glass in the harmonic approximation reads [1]

$$\kappa = \frac{\pi}{3V} \sum_{\mu\nu} C_{\mu} |v_{\mu\nu}|^2 \delta(\omega_{\mu} - \omega_{\nu}), \tag{1}$$

where μ and ν enumerate normal modes, ω_{μ} is the corresponding (angular) frequency, $C_{\mu} = \hbar \omega_{\mu} \frac{\partial n(\omega_{\mu})}{\partial T}|_{V}$ the contribution of the μ th normal mode to the isochoric heat capacity— $n(\omega) = [e^{\frac{\hbar\omega}{k_BT}} - 1]^{-1}$ being the Bose-Einstein occupation number, and k_B the Boltzmann constant—V is the volume, and $v_{\mu\nu}$ is a generalized velocity matrix. The velocity matrix, whose precise definition can be found in Refs. [1,15], is essentially the first real-space moment of the matrix of interatomic force constants. It is anti-Hermitean, and, in a crystal, it can be chosen to be diagonal in the (Bloch) normalmode representation, so that its diagonal elements are the normal-mode group velocities. In a disordered system, where normal modes are necessarily real, the corresponding diagonal elements of the velocity matrix vanish, and the heat conductivity results from the coupling between (quasi) degenerate states (see below). It must be stressed that Eq. (1) holds only in the thermodynamic limit, where the vibrational spectrum is continuous and the double sum actually means a double integral. Practical calculations on finite models instead require smearing the Dirac delta to a peaked function such as a Lorentzian, thus turning Eq. (1) to [1,2]

$$\kappa = \frac{1}{3V} \sum_{\mu\nu} C_{\mu} |v_{\mu\nu}|^2 \frac{\eta}{(\omega_{\mu} - \omega_{\nu})^2 + \eta^2},$$
 (2)

where η is the broadening width of the smeared Dirac delta. The value of η is customarily chosen large enough to encompass several normal modes within the Lorentzian, while still remaining small enough to preserve the characteristics of a peaked function. The broadening of the delta function determines the extent to which pairs of quasi-degenerate states contribute to the heat conductivity, as strict degeneracy holds a zero probability in any finite model of a disordered system. As it will turn out, and at variance with what is commonly assumed, η plays a crucial role in determining the value of the thermal conductivity in the AF model. In particular, its relevance becomes apparent for low-frequency vibrations within the long-wavelength regime, where normal modes gradually approach the behavior of (plane) sound waves.

In recent years, the AF approach has been generalized to incorporate a perturbative treatment of anharmonic effects, resulting in the QHGK theory [15,16] or equivalently the

Wigner transport equation [17–19]. The QHGK expression for the thermal conductivity of an isotropic material reads

$$\kappa = \frac{1}{3V} \sum_{\mu\nu} C_{\mu\nu} |v_{\mu\nu}|^2 \frac{\gamma_{\mu} + \gamma_{\nu}}{(\omega_{\mu} - \omega_{\nu})^2 + (\gamma_{\mu} + \gamma_{\nu})^2}, \quad (3)$$

where γ_{μ} is the anharmonic linewidth of the μ th normal mode and

$$C_{\mu\nu} = \frac{\hbar^2 \omega_{\nu} \omega_{\mu}}{T} \frac{n(\omega_{\nu}) - n(\omega_{\mu})}{\hbar(\omega_{\mu} - \omega_{\nu})} \tag{4}$$

is a generalized two-mode heat capacity. When $\omega_{\mu}=\omega_{\nu}$, Eq. (4) reduces to the modal specific heat C_{μ} appearing in Eqs. (1) and (2). The QHGK thermal conductivity, Eq. (3), applies to crystalline and amorphous solids alike. For crystals, it reduces to the results of the Boltzmann transport equation in the relaxation-time approximation, supplemented with interband effects; for glasses in the harmonic limit, the QHGK approximation reduces to the AF model [15]. Again, in practical calculations on finite systems, the AF model is restored bringing γ_{μ} from its temperature- and mode-dependent value to a temperature- and mode-independent value.

B. Bulk limit of thermal conductivity

The use of a constant linewidth has minimal impact on intermediate-frequency vibrations, dubbed diffusons since they propagate diffusively, and high-frequency ones, called locons for their localization in real space [4]. The reason for this is that the anharmonic lifetimes of these modes are usually small and that the density of states is large and slowly varying. As a consequence, in the AF model, the diffuson contribution to the thermal conductivity is weakly dependent on η , reaching convergence once the smearing is of the order of the average frequency spacing of the normal mode. On the contrary, low-frequency vibrations, known as propagons since they propagate like sound waves [4], display a distinct behavior. For these excitations, the vibrational density of states (VDOS) decreases quadratically as the frequency approaches zero and the anharmonic lifetimes diverge due to the lack of vibrational decay channels. Consequently, the finite, constant linewidth introduced by smearing the Dirac delta function could overshadow the anharmonic scattering and possibly result in a nonphysical contribution to the heat conductivity.

To address the propagon contribution to the heat conductivity, it is expedient to define the vibrational dynamical structure factor. As mentioned above, propagons, diffusons, and locons differ by the degree of localization they feature. This can be observed in the VDSF that, for a harmonic system, is defined as [5]

$$S_b^{\circ}(\omega, \mathbf{Q}) = \sum_{\nu} \delta(\omega - \omega_{\nu}) |\langle \nu | \mathbf{Q}, b \rangle|^2, \tag{5}$$

where $\langle \nu | \mathbf{Q}, b \rangle$ denotes the projection of the ν normal mode over a sound (plane) wave vibration of wave vector \mathbf{Q} and polarization b (b = L, T for longitudinal and transverse branches, respectively) [20]. Anharmonic effects in the VDSF can be accounted for by smearing the delta function in Eq. (5)

to a Lorentzian function

$$S_b(\omega, \mathbf{Q}) = \frac{1}{\pi} \sum_{\nu} \frac{\gamma_{\nu}}{\gamma_{\nu}^2 + (\omega - \omega_{\nu})^2} |\langle \nu | \mathbf{Q}, b \rangle|^2.$$
 (6)

The low-frequency, small wave vector, portion of each branch of the VDSF features an almost linear dispersion typical of acoustic waves $\omega_{Qb} = c_b Q$, where $c_{L/T}$ are the longitudinal/transverse speeds of sound [20]. In other words, $S_b(\mathbf{Q}, \omega)$ is a peaked function centered at $c_b Q$ which can be faithfully represented by a single Lorentzian profile

$$S_b(\omega, \mathbf{Q}) \approx \frac{\alpha_b(\mathbf{Q})}{\pi} \frac{\Gamma_b(\mathbf{Q})}{(\omega - c_b Q)^2 + \Gamma_b(\mathbf{Q})^2},$$
 (7)

allowing one to evaluate the speed of sound as well as the wave vector dependence of the sound damping coefficients $\Gamma_b(\mathbf{Q})$, accounting for both disorder and anharmonic effects on the same footing. The **O**-dependent function $\alpha_b(\mathbf{O})$ is a global prefactor that scales the Lorentzian. For any given polarization, in an isotropic medium, the damping coefficient can only depend on the magnitude of the wave vector, yielding $\Gamma_b(Q)$. Propagons are identified as those low-frequency/longwavelength normal modes that contribute to the VDSF in the linear-dispersion regime. The increasing broadening of the dispersion identifies a cutoff frequency for propagons ω_P , often referred to as the Ioffe-Regel limit [4,21]. According to Eq. (7), below this limit vibrational modes can be approximately described by damped plane waves, characterized by the group velocities c_b and decay times $\tau_b(Q) = [2\Gamma_b(Q)]^{-1}$. Consequently, the propagon contribution to the heat conductivity can be cast into the form [20]

$$\kappa_P = \frac{1}{3V} \sum_{Qh}^{c_b Q < \omega_P} g_b C(c_b Q) c_b^2 \tau_b(Q), \tag{8}$$

where g_b is the degeneracy of the propagon branch $g_L = 1$ and $g_T = 2$. In the bulk limit, when the size of the system is brought to infinity, the discrete sum over states becomes an integral through the definition of a density of states; the contribution of the propagon to the thermal conductivity thus takes a form reminiscent of the kinetic theory of gases [20]

$$\kappa_P = \sum_b \frac{c_b^2}{3} \int_0^{\omega_P} C(\omega) \rho_b(\omega) \frac{1}{2\Gamma_b(\omega/c_b)} d\omega, \qquad (9)$$

where $\rho_b = \frac{g_b \omega^2}{2\pi^2 c_b^3}$ are the L/T Debye's density of states per unit volume. Equation (9), which applies to both crystals and glasses, is the infinite size limit of the propagon contribution to both Eqs. (3) and (1), the difference lying in whether or not $\Gamma_b(\omega/c_b)$ includes anharmonic effects. Formulas such as Eq. (9), where hydrodynamic arguments are used to extrapolate QHGK results to the infinite-size limit [20], will be referred to as *hydrodynamic QHGK formulas*.

C. Singularity of the AF model and the role of anharmonicity

Under general assumptions [22,23], for low-enough frequencies, one can write the linewidth as [20,24,25]

$$\Gamma_b(\omega/c_b) \approx A_b \omega^2 + B_b \omega^4.$$
 (10)

In the harmonic approximation, $A_b = 0$ and the leading order in the frequency dependence of the sound damping coefficient is quartic due to incoherent Rayleigh scattering from elastic fluctuations of the medium [22,26]. This behavior, which is confirmed by experiments [27], can be understood through random media theory on a continuous model [28,29], or from a microscopic perspective via harmonic perturbation theory, such as in the case of crystals with mass disorder [30,31] or random spring constants [26]. When $A_b = 0$ in Eq. (9), one easily sees that the contribution of the propagons to the heat conductivity diverges at all temperatures. On the other hand, the inclusion of anharmonic contributions ensures a quadratic dependence of Γ_b on frequency, resulting in a finite thermal conductivity whenever $A_b \neq 0$ [20,24]. We conclude that disorder alone is insufficient to guarantee a finite bulk thermal conductivity in glasses.

How come practical calculations employing the AF model yield finite values of κ which compare fairly well with experimental results? The answer ultimately hinges on the fact that the calculations are necessarily performed on finite glass models. This has two main consequences. The first is that the finite size, L, naturally introduces an infrared cutoff to κ_P , $\omega_{\min} \sim 2\pi c/L$, which makes it always finite. In particular, the infrared contribution to κ_P , which is divergent in the harmonic approximation, turns out to be typically small in most cases, when anharmonic effects are adequately considered, as detailed below. The second consequence is that the finite number of normal modes requires the smearing of their individual contributions to Eq. (1). This leads to Eq. (2), where anharmonic linewidths are substituted with a (rather unphysical) mode-independent broadening. Therefore, the net effect of a finite calculation is that a contribution to κ —the one associated with frequencies below ω_{\min} —is completely neglected, while all that remains is affected by the choice of the constant damping due to the broadening width η . Crucially, this broadening plays a significant role even in the bulk limit. In fact, the VDSF linewidth is the sum of the harmonic contribution, proportional to ω^4 , and the constant broadening due to the smearing [20]. Thus, the smearing width enters the Debye expression of the harmonic thermal conductivity as

$$\kappa_P = \sum_b \frac{g_b}{6\pi^2 c_b} \int_{\omega_{\min}}^{\omega_P} C(\omega) \frac{\omega^2}{2B_b \omega^4 + \eta} d\omega.$$
 (11)

The integral in Eq. (11) converges for any finite value of η and/or ω_{\min} , and both are artificial byproducts of finite-size calculations. The true bulk limit is restored in the $\omega_{\min} \to 0$, $\eta \to 0$ limit. Figure 1 shows the harmonic (solid lines) and anharmonic (dashed lines) thermal conductivity of a typical amorphous solid as a function of ω_{\min} and η . The propagon contribution is obtained from Eqs. (11) (harmonic case) and (9) with Γ given by Eq. (10) (anharmonic). The diffuson contribution κ_D (which does not depend on ω_{\min}) is essentially independent of η , and thus adds the same constant shift to each line. The left panel of Fig. 1 shows κ as a function of the infrared cutoff for different values of the smearing width. When $\eta = 0$, κ diverges in the $\omega_{\min} \to 0$ limit. In the opposite way, the right panel shows κ as a function of the smearing width for different values of the infrared cutoff. Again, when $\omega_{\min} = 0$, κ diverges in the limit $\eta \to 0$.

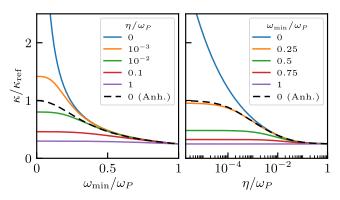


FIG. 1. Heat conductivity of glasses in the harmonic approximation [see Eq. (11), numerical values appropriate for aSi]. Solid lines in color are computed in the harmonic approximation, while the black, dashed lines refer to calculations also accounting for anharmonic effects. Left panel: κ as a function of the infrared cutoff for different values of the smearing width. Right panel: κ as a function of the smearing width for different values of the infrared cutoff (note the logarithmic scale in the x-axis). Frequencies are reported in units of the propagon cutoff frequency, ω_P [20]. The thermal conductivity is reported in units of the bulk thermal conductivity in presence of anharmonic effects, $\kappa_{\rm ref}$.

We must now stress that most of the experimental literature on heat transport in glasses from the nineties concerns micrometer-thick films [32] rather than samples of macroscopic size. Formally, boundary effects such as those involved in thin-film experiments would enter the expression of the thermal conductivity the same way as the AF smearing width in Eq. (11). For a thin-film sample, the thermal conductivity can in fact be described by an equation similar to Eq. (11), where η is replaced a constant boundary-scattering contribution to the linewidth, of the form $\eta_{BS} \sim c/d$, d being the film thickness [8,32-34]. As a consequence, the bulk limit of the AF model with fixed η yields the same thermal conductivity of a thin film rather than that of an infinite system. In the harmonic approximation, the first remains finite, while the second diverges. This might have unintentionally contributed to the misconception that the heat conductivity of bulk glasses can be fully explained in terms of disorder effects alone, neglecting anharmonic interactions. These interactions dampen low-frequency vibrations and regularize the heat conductivity at all finite temperatures. In many cases, this regularization renders the infrared contribution to κ almost negligible in the bulk limit compared to that of diffusons. Essentially, anharmonic interactions substitute a divergent quantity (the bulk thermal conductivity of propagons in the harmonic approximation) with a finite quantity that can be mimicked by a finite-size effect in calculations on finite systems. In conclusion, the presence of anharmonic interactions is vital for regularizing the behavior of κ in a macroscopic system, even in the case of disordered materials [20].

III. NUMERICAL EXPERIMENTS

To substantiate our arguments, we performed several numerical experiments on three glasses featuring different

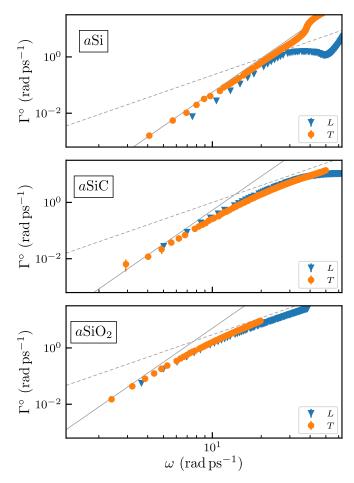


FIG. 2. Sound damping coefficients in the harmonic approximation for aSi, aSiC, and aSiO₂. The estimate is obtained by fitting the harmonic vibrational dynamical structure factor, Eq. (5), with its soundwave form, Eq. (7), and expressing the linewidth as a function of ω , as in Eq. (10). The sizes of the samples are, respectively, 13 824, 97 336, and 139 968 atoms. The estimated errors are smaller than the size of the symbols. The dashed and continuous gray lines indicate, respectively, the ω^2 and ω^4 scaling. Note the logarithmic scale on both axes.

convergence properties to the bulk limit [20]: amorphous silicon (aSi), silica (aSiO₂), and silicon carbide (aSiC). Samples were generated through a melt-quench procedure using the LAMMPS code [35]. For postprocessing, we primarily utilized the κ ALDo code [36] and implemented Haydock's iterative algorithm to compute the VDSF. Technical details are reported on Appendixes A and B.

A. Low-frequency behavior of the sound damping coefficients

The quartic frequency dependence of the sound damping coefficients in harmonic glasses can be understood perturbatively in terms of the scattering of acoustic waves in a homogeneous medium with small, random, independent local fluctuations of the elastic constants [26]. In Fig. 2 we report the dependence of the attenuation coefficients in the harmonic approximation on frequency for the three materials considered in this work. Both aSiC and aSiO₂ exhibit an $\omega^4 \to \omega^2$ crossover, ω_{XO} , respectively, around 2 and

1 THz ($\omega_{XO} \approx 12$ and $\omega_{XO} \approx 6 \, \mathrm{rad \, ps^{-1}}$), in agreement with theoretical models which explain it in terms of the mixing between longitudinal and transverse modes due to the broadening of the linear dispersion induced by disorder [28]. This behavior is also in agreement with experiments, which find a first-temperature-dependent-crossover at very low frequency between an ω^2 regime, determined by anharmonic effects, and the ω^4 regime where disorder dominates [37], followed a by second—temperature-independent—crossover from ω^4 to ω^2 due to the longitudinal-transverse mixing mentioned above [27]. No such crossover is observed in aSi. As the minimum frequency compatible with a given finite glass models scales as the inverse size, rather large simulation cells are required to discriminate the crossover and evaluate the corresponding coefficients. For materials such as aSiO₂, where the crossover occurs at relatively low frequencies, it is essential to have systems with several tens of thousands of atoms. In practice, standard lattice-dynamical techniques based on matrix diagonalization are unsuitable to deal with such large systems, and the VDSF can be best computed directly in these cases using Haydock's recursion method [38,39] based on the Lanczos algorithm [40] (see Appendix B). We are thus able to compute the VDSF for systems comprising up to a hundred-thousand atoms, an order of magnitude larger than those computed in our earlier work employing direct diagonalization [20].

It must be noted that the existence of the $\omega^4 \rightarrow \omega^2$ crossover may yield misleading results in the computation of the thermal conductivity. This issue is particularly relevant for aSiO₂, a material often depicted as highly disordered, whose heat conductivity would have very small finite-size effects, and reaching a well-converged value with models of a few thousand atoms [8]. Actually, since its crossover frequency is $\omega_{XO} \sim 7.5 \,\mathrm{rad}\,\mathrm{ps}^{-1}$ for both polarizations [27], to evaluate the bulk limit of the thermal conductivity of this system, one would need to employ samples whose linear size exceeds the wavelength of the corresponding sound wave. The wavelength for the longitudinal sound wave λ_{XO}^L is given by $\frac{\omega_{XO}}{2\pi c_L} \sim 60 \,\text{Å}$, while the wavelength for the transverse sound wave λ_{XO}^T is given by $\frac{\omega_{XO}}{2\pi c_T} \sim 35$ Å. Thus, the sample size should be greater than λ_{XO}^L , which means it should contain $\gtrsim 14\,000$ atoms. Therefore, if one were to study the AF thermal conductivity of a glass with a finite model of linear size smaller than λ_{XO}^{L} , one would only sample the propagon contribution above the crossover, thus squarely missing the quartic low-frequency dependence of the sound damping coefficient that determines the divergence of the heat conductivity in the harmonic approximation.

B. AF thermal conductivity

To demonstrate how the ω^4 dependence of the harmonic sound damping coefficients affects the bulk limit of the AF heat conductivity, we computed the propagon contribution to the AF conductivity in aSi, aSiO₂, and aSiC over a range of values of the smearing parameter η and for finite models of progressively larger sizes. We compared these results with the analytical model provided by Eq. (11) $\kappa_P(T, \eta)$ whose parameters are estimated from the harmonic VDSFs. The results for

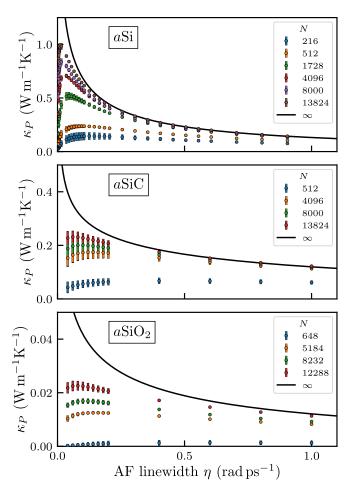


FIG. 3. Propagon AF thermal conductivity of aSi, aSiC, and aSiO₂ samples with different number of atoms (N), as a function of the AF linewidth, η . Calculations are made at a temperature of 500 K. The black, solid, line is the infinite-size analytical result given by Eq. (11). The cutoff angular frequency for propagons is set to $\omega_P/2\pi=3$ THz, $\omega_P/2\pi=3$ THz, and $\omega_P/2\pi=1.2$ THz, for the three materials, respectively.

aSi at 500 K are shown in the upper panel of Fig. 3. As the size of the model increases, the AF data approach the analytical benchmark. The convergence is achieved at larger sizes as the value of η decreases. In fact, calculations on a finite system with small η are meaningless: when the average frequency spacing of propagons is larger than the AF smearing, the Lorentzian functions in Eq. (2) become so sharp that the corresponding effective VDOS features unphysical gaps that result in a spurious reduction of the thermal conductivity.

From the central and lower panels of Fig. 3 similar conclusions can be drawn for aSiC and aSiO₂, respectively. Unlike aSi, both materials present the aforementioned $\omega^4 \rightarrow \omega^2$ crossover around $\omega_{XO} = 12 \, \mathrm{rad \, ps^{-1}}$ and $6 \, \mathrm{rad \, ps^{-1}}$, respectively. This requires a different functional form for the harmonic linewidth, able to capture the crossover, such as the one proposed in Ref. [27]

$$\Gamma^{\circ}(\omega) = C_b \omega^2 \left[1 + \left(\omega_{XO}^b / \omega \right)^{2\delta} \right]^{-1/\delta}, \tag{12}$$

where C_b is a constant, ω_{XO}^b is the polarization-dependent crossover angular frequency, and $\delta = 1.5$ determines the

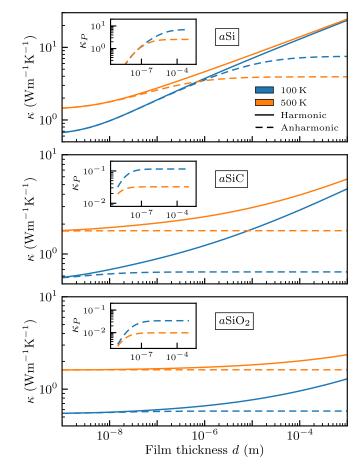


FIG. 4. Size-dependent thermal conductivity of $a\mathrm{Si}$, $a\mathrm{SiC}$, and $a\mathrm{SiO}_2$ at $100\,\mathrm{K}$ (blue) and $500\,\mathrm{K}$ (orange). Calculations employ Eq. (11) with $\omega_{\min}=0$, and boundary scattering according to the systems' size, for propagons, while the diffuson contribution is size independent. Solid lines shows the harmonic results, while dashed line include also anharmonic linewidths. In the insets, we display only the propagon thermal conductivity in the anharmonic case. Note the logarithmic scale on both axes.

sharpness of the transition. We then compared the AF data with the analytical model provided by Eq. (9) with the linewidth computed with Eq. (12). Like for aSi, when η is large, for both aSiC and aSiO₂ the AF results converge in size to the analytical ones, and the convergence is reached at larger sizes as η diminishes. In the $\eta \to 0$ limit, the analytical model diverges due to the Rayleigh ($\propto \omega^4$) scattering term in the harmonic linewidth.

C. Discussion

As discussed above, the AF method is commonly acknowledged to effectively account for experimental measurements of the heat conductivity of amorphous solids. To gain a deeper insight into this effectiveness, in Fig. 4 we analyze the dependence of the extrapolated [Eq. (11), $\omega_{\min} = 0$] thermal conductivity of aSi, aSiC, and aSiO $_2$ at 100 K and 500 K on the thickness of the sample d. The boundary scattering adds to the linewidth of each polarization a term equal to $\eta_{\rm BS}^b = c_b/d$ [33]. The insets show the propagon contribution to the

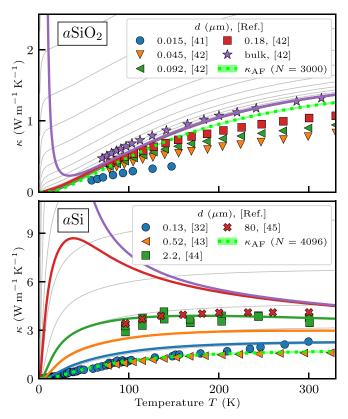


FIG. 5. Thermal conductivity of $a \text{SiO}_2$ and a Si as functions of temperature. Markers are experimental data taken from Refs. [41,42] ($a \text{SiO}_2$) and Refs. [32,43–45] (a Si). The solid lines, color-matched to the markers, represent hydrodynamic QHGK results for films of the same thickness. Light-green, dotted lines are standard AF results on a finite system of the size indicated in the legend, and obtained with a smearing parameter η set to the average angular frequency spacing. Gray lines correspond to bulk AF results with κ_P computed according to Eq. (11), where $\omega_{\min} = 0$ and η ranges from 0.1 rad ps⁻¹ (bottommost curve) to 10^{-9} rad ps⁻¹ (topmost curve) on a logarithmic scale.

thermal conductivity κ_P , where third-order anharmonic effects are computed with the Fermi's Golden Rule and included through the Matthiessen rule [33]. In the harmonic approximation, the thermal conductivity diverges as the film thickness increases, as indicated by the solid lines. However, when anharmonicity is accounted for, the thermal conductivity converges to its bulk value at a finite thickness. The figure demonstrates that in materials such as aSiO₂ and aSiC, where propagons contribute marginally to heat transport compared to diffusons, the bulk limit is reached at nanometer scales. In our aSi model, where propagons play a more significant role, the bulk limit is achieved at much larger sizes, around a 100 micrometers. It is worth noting that, at the typical thin-film sizes used experimentally, the harmonic value of κ is not significantly different from the anharmonic one. This suggests that a harmonic model on a *finite* system can provide a reasonable estimate of the thermal conductivity of a thin film even when extrapolated to $\omega_{\min} \rightarrow 0$, as long as boundary scattering is appropriately accounted for.

Figure 5 illustrates the temperature dependence of κ for aSiO₂ and aSi. We compare experimental measurements

from the literature with our hydrodynamic QHGK results and AF calculations conducted on finite samples. The anharmonic linewidths are computed on a range of temperatures and extrapolated to get a continuous line, as described in Refs. [46,47]. These linewidths are then combined with the total linewidth using the Matthiessen rule [33]. For aSiO₂, the QHGK results match the bulk experimental measurement [42]. AF calculations, performed on a sample comprising 3000 atoms, also shows good agreement with both bulk-QHGK results and experimental data. This indicates that, in the case of aSiO₂, diffusons completely dominate the thermal conductivity. Therefore, similar results are obtained neglecting contributions below ω_{\min} (as done in finite AF calculations) as well as considering the anharmonic damping of propagons (as in bulk QHGK calculations). However, a direct extrapolation of the AF results regularized with a finite η yields values of κ ranging from κ_D to infinity, depending on the value of the smearing parameter.

In the case of $a\mathrm{Si}$, where propagons are more important, the intriguing effectiveness of AF calculations in matching experimental data is further questioned. For instance, a calculation using 4096 atoms closely agrees with measurements on a 0.52-µm-thick film [43], seemingly validating the entire procedure. Again, what is actually happening is that the (diverging) contribution to κ from 0 to ω_{\min} is being set to zero rather than to the (finite and small) value it would have when accounting for anharmonicity. For $a\mathrm{Si}$, the missing contribution is not as negligible as it is for $a\mathrm{SiO}_2$, resulting in a pronounced difference between the QHGK results and the AF calculation.

The temperature dependence of the QHGK heat conductivity results from two competing contributions. One is that of diffusons, which is exponentially suppressed at low temperatures—due to the Bose-Einstein occupation function—and saturates to a constant at higher temperatures. The other is the one of propagons, which diverges as $T \to 0$ for essentially the same reasons why it does so in crystals [20]: first, the propagation of sound waves with wavelengths much larger than the atomic correlation length is relatively unaffected by disorder at leading order in ω , and, second, the temperature dependence of A_b in Eq. (10) causes the integral in Eq. (9) to diverge for vanishing temperatures [46,47]. The concavity of $\kappa(T)$ is thus determined by the relative magnitudes of the two contributions [20]. In materials where propagons contribute marginally to the heat conductivity (such as aSiO₂, upper panel of Fig. 5), the divergence of the bulk value of $\kappa_P(T)$ becomes noticeable primarily at very low temperatures. The change in concavity is thus determined by the onset of diffusons. Conversely, when propagons dominate the thermal conductivity, the concavity might be entirely determined by κ_P , such as in the case of our model of aSi (purple curve in the lower panel of Fig. 5). At low temperatures, in thin films the divergence is suppressed by boundary scattering effects, as illustrated in Fig. 5. In bulk systems, where no boundary scattering exists, the low-temperature divergence is suppressed by quantum tunneling between quasidegenerate minima in the glass energy landscape, which leads to the plateau commonly observed at a few tens of kelvins in most glasses [9–14].

IV. CONCLUSION

The main result of this paper is the theoretical and numerical proof that disorder effects alone are not sufficient to bring the heat conductivity of a material from the infinite value it has in a harmonic crystal to the finite value observed in real glasses. In the harmonic approximation, the low-frequency portion of the vibrational spectrum yields an infinite contribution to the thermal conductivity reminiscent of its behavior in crystals: in the long-wavelength/low-frequency regime, sound waves propagate in glasses essentially the same way they do in crystals, to the relevant order in frequency. In fact, the lack of sound damping in harmonic crystals and its rapid decay in harmonic glasses ($\sim \omega^4$) both fail to effectively regularize the divergent conductivity. By contrast, a proper account of anharmonic effects makes the bulk thermal conductivity of glasses finite at any finite temperature. Still, with anharmonicity alone, the thermal conductivity would diverge at zero temperature. In practice, at extremely low temperatures the residual divergence is suppressed by quantum-tunneling effects [9], leading to the well-known thermal conductivity plateau at a few tens of kelvins. This plateau is believed to be due to the tunneling between quasidegenerate low-energy minima in the glass energy landscape, responsible for the residual entropy in glasses [48–50]. As our treatment is limited to the vibrational properties within a single such energy minimum, it obviously fails to address the low-temperature plateau. The description of these tunneling effects from first principles thus remains a major challenge in the physics of glasses to be addressed in the future. It is noteworthy that, in materials where the dominant influence of propagons on heat transport persists at temperatures higher than those at which quantum tunneling suppresses them, our analysis indicates that the bulk thermal conductivity should display a maximum at low temperature, which could potentially be detected experimentally.

The data and scripts that support the plots and relevant results within this paper are available on the Materials Cloud platform [51,52].

The codes that support the relevant results within this paper are available to the respective developers. Analysis scripts are available on GitHub [53] and on the Materials Cloud platform [52].

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A.F., P.P., and S.B. conceived the study and provided the overall conceptual framework. A.F., P.P., and E.D. conducted the analytical work and developed the necessary computer

codes. A.F. and P.P. run and analyzed the computer simulations. A.F., P.P., and E.D. produced the figures. S.B. provided supervision and guidance throughout the project. The manuscript was collaboratively written by all authors.

APPENDIX A: COMPUTATIONAL DETAILS

The glass samples are generated by a melt-and-quench procedure. Initially, a crystalline conventional cell is replicated ℓ times along each Cartesian direction. The trajectories are then generated in different thermodynamic ensembles (see below), using the velocity-Verlet algorithm implemented in the LAMMPS code [35]. A time step of 1/1/0.5 fs is used for $a{\rm SiO}_2/a{\rm SiC}/a{\rm Si}$. To ensure statistical robustness, all of our results are averaged over 4/4/10 independent samples. These samples are obtained by repeating the melt-and-quench procedure multiple times, each with a different random initialization. After the equilibration, the atomic configurations are optimized so as to make atomic forces smaller than a preassigned threshold of $10^{-10}\,{\rm eV/\mathring{A}}$.

Normal modes and thermal conductivities are computed with the κ ALDo code [36] using second- and third-order interatomic force constants obtained from LAMMPS.

1. aSiO₂

 $a\mathrm{SiO}_2$ is modeled with a Vashishta force field [54]. The glass was modeled starting from the cubic β-cristobalite conventional 24–atom unit cell with a mass density of $2.20\,\mathrm{g\,cm^{-3}}$ replicated $\ell=18$ times along each Cartesian direction, comprising $\approx 140\,000$ atoms in the simulation box. The crystal is melted at 7000 K and then quenched at 500 K in 10 ns [55,56]. The system is then thermalized at 500 K for 400 ps and then 100 ps in the NVE ensemble. The final average density of the $a\mathrm{SiO}_2$ samples thus obtained is $2.408\,\mathrm{g\,cm^{-3}}$ with a standard deviation across different samples of $0.002\,\mathrm{g\,cm^{-3}}$.

2. aSiC

aSiC is also modeled with a Vashishta force field [57,58]. The starting configuration is a cubic crystalline zinc-blend structure, with eight atoms in the unit cell, and a mass density of $3.22\,\mathrm{g\,cm^{-3}}$ repeated 23 times along each Cartesian direction, thus comprising ≈97 000 atoms in the simulation cell. Following the procedure described in Ref. [57], the crystal is initially brought from 300 K to 4000 K in the NpT ensemble at constant null pressure, then quenched at 500 K in 400 ps, and finally equilibrated in the NVE ensemble for 80 ps. The average density of aSiC is 2.976 g cm⁻³ with a standard deviation across different samples of 0.002 g cm⁻³.

3. aSi

aSi is modeled with the Tersoff force field [59]. The starting configuration is a diamond structure, with eight atoms in the unit cell, with a mass density of $2.31\,\mathrm{g\,cm^{-3}}$ repeated 12 times along each Cartesian direction, corresponding to ≈14 000 atoms in the simulation cell. At variance with aSiO₂ and aSiC, in the case of aSi, this moderate size already allows one to observe the ω^4 scaling of the harmonic linewidth. The crystal is initially melted at 6000 K, then quenched at 300 K in 22 ns, and equilibrated in the NVE ensemble for 10 ns [60]. This prescription ensures the resulting structures to be compatible with a continuous random network with coordination number 4 [15]. The average mass density of the aSi is 2.275 g cm⁻³ with a standard deviation across samples of 0.003 g cm⁻³.

APPENDIX B: HAYDOCKS RECURSION METHOD

The direct computation of the harmonic VDSF is unfeasible for systems of tens of thousands of atoms because it requires the diagonalization of the entire dynamical matrix, a procedure that scales as the cube of the number of atoms. Haydock's recursion method is an iterative procedure, based on the Lanczos orthogonalization algorithm, that allows one to estimate the VDSF as the imaginary part of a diagonal element of the vibrational Green's function of the system [38,39]. Using this procedure, we were able to address several systems of tens of thousands of atoms, where the quartic scaling of the harmonic linewidth is appreciable, as reported in Fig. 2.

We want to compute the diagonal matrix elements of the vibrational Green's function of the form

$$\lim_{\epsilon \to 0} \operatorname{Im} \langle \mathbf{Q}, b | ((\omega + i\epsilon)^2 - \bar{\mathbf{K}})^{-1} | \mathbf{Q}, b \rangle$$

$$= \frac{\pi}{2|\omega|} \left[S_b^0(\omega, \mathbf{Q}) + S_b^0(-\omega, \mathbf{Q}) \right], \tag{B1}$$

where

$$\bar{\mathbf{K}} = \mathbf{M}^{-1/2} \mathbf{K} \mathbf{M}^{-1/2}, \tag{B2}$$

K is the matrix of interatomic force constants (i.e., the Hessian of the energy with respect to atomic displacements), and **M** is the diagonal, positive-definite, matrix of the atomic mass distribution. In a system of N atoms, $|\mathbf{Q}, b\rangle$ is a 3N-dimensional vector whose projection onto the displacement of Ith atomic site in the α th Cartesian direction is

$$\langle I, \alpha || \mathbf{Q}, b \rangle = \frac{1}{\sqrt{N}} \epsilon_{\alpha}^{b}(\mathbf{Q}) e^{i\mathbf{Q} \cdot \mathbf{R}_{I}},$$
 (B3)

where $\epsilon^b(\mathbf{Q})$ is the polarization vector, and $\mathbf{Q} = \frac{2\pi}{L}(n, m, l)$, with $(n, m, l) \in \mathbb{Z}^3$, is a wave vector compatible with the enforced periodic boundary conditions. The harmonic VDSF is then computed by a continued fraction expansion

$$\frac{\pi}{2|\omega|} \left[S_b^0(\omega, \mathbf{Q}) + S_b^0(-\omega, \mathbf{Q}) \right] = \lim_{\epsilon \to 0} \text{Im} \frac{1}{(\omega + i\epsilon)^2 - a_0 - \frac{b_1^2}{(\omega + i\epsilon)^2 - a_1 - \frac{b_2^2}{2}}},$$
(B4)

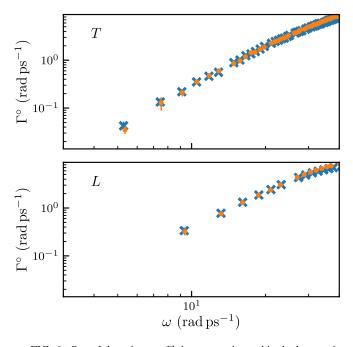


FIG. 6. Sound damping coefficients as estimated in the harmonic approximation for aSiC obtained by fitting the harmonic vibrational dynamical structure factor, Eq. (5), computed via Haydock's method (orange dots) and via direct diagonalization (cyan crosses). Both results are averaged over 4 samples of 13 824 atoms, and the error bars represent standard deviations. Upper panel, transverse modes; lower panel, longitudinal modes.

where the coefficients $\{a_0, a_1, \ldots\}$ and $\{b_1, b_2, \ldots\}$ are evaluated by the recursion Lanczos chain

$$|\xi_{-1}\rangle = 0,$$

$$|\xi_{0}\rangle = |\mathbf{Q}, b\rangle,$$

$$b_{n}|\xi_{n}\rangle = (\bar{\mathbf{K}} - a_{n-1})|\xi_{n-1}\rangle - b_{n-1}|\xi_{n-2}\rangle,$$

$$a_{n} = \langle \xi_{n}|\bar{\mathbf{K}}|\xi_{n}\rangle,$$

$$b_{n} = \langle \xi_{n}|\bar{\mathbf{K}}|\xi_{n-1}\rangle.$$
(B5)

This procedure drastically reduces the computational cost of the evaluation of the harmonic VDSF, going from a $\mathcal{O}((3N)^3)$ scaling of the exact diagonalization algorithm to the $\mathcal{O}[k(3N)^2]$ scaling, where N is the number of atoms in the simulation cell and k is the number of steps of the Lanczos chain. Moreover, since the matrix of the interatomic force constants is sparse, the numerical burden of Haydock's algorithm can be further reduced to a complexity $\mathcal{O}(kN)$. The procedure proves to be numerically robust, in spite of the well-known instabilities of the Lanczos tridiagonalization scheme [61], and approximately 200 recursion steps are typically sufficient to estimate the sound damping coefficients, which we increased up 600 steps to carefully test the convergence. To validate the iterative algorithm we compared the harmonic attenuation coefficients fitted from the VDSF computed via direct diagonalization of the dynamical matrix and via Haydock's method as in Eq. (B4). In Fig. 6 we display the sound damping coefficients computed on a model of aSiC of 13824 atoms, showing good agreement between the two methods.

^[1] P. B. Allen and J. L. Feldman, Thermal conductivity of glasses: Theory and application to amorphous Si, Phys. Rev. Lett. **62**, 645 (1989).

^[2] P. B. Allen and J. L. Feldman, Thermal conductivity of disordered harmonic solids, Phys. Rev. B 48, 12581 (1993).

^[3] J. L. Feldman, M. D. Kluge, P. B. Allen, and F. Wooten, Thermal conductivity and localization in glasses: Numerical study of a model of amorphous silicon, Phys. Rev. B 48, 12589 (1993).

^[4] P. B. Allen, J. L. Feldman, J. Fabian, and F. Wooten, Diffusons, locons and propagons: Character of atomic vibrations in amorphous Si, Philos. Mag. B 79, 1715 (1999).

^[5] J. L. Feldman, P. B. Allen, and S. R. Bickham, Numerical study of low-frequency vibrations in amorphous silicon, Phys. Rev. B 59, 3551 (1999).

^[6] C. Kittel, Interpretation of the thermal conductivity of glasses, Phys. Rev. 75, 972 (1949).

^[7] W. Schirmacher, Thermal conductivity of glassy materials and the "boson peak", Europhys. Lett. 73, 892 (2006).

^[8] J. M. Larkin and A. J. H. McGaughey, Thermal conductivity accumulation in amorphous silica and amorphous silicon, Phys. Rev. B 89, 144303 (2014).

^[9] J. Jäckle, On the ultrasonic attenuation in glasses at low temperatures, Z. Phys. **257**, 212 (1972).

^[10] W. A. Phillips, Two-level states in glasses, Rep. Prog. Phys. 50, 1657 (1987).

^[11] P. Sheng and M. Zhou, Heat conductivity of amorphous solids: Simulation results on model structures, Science **253**, 539 (1991).

^[12] U. Buchenau, Y. M. Galperin, V. L. Gurevich, D. A. Parshin, M. A. Ramos, and H. R. Schober, Interaction of soft modes and sound waves in glasses, Phys. Rev. B 46, 2798 (1992).

^[13] A. J. Leggett and D. C. Vural, "Tunneling two-level systems" model of the low-temperature properties of glasses: Are "smoking-gun" tests possible? J. Phys. Chem. B **117**, 12966 (2013).

^[14] V. Lubchenko and P. G. Wolynes, The origin of the boson peak and thermal conductivity plateau in low-temperature glasses, Proc. Natl. Acad. Sci. USA 100, 1515 (2003).

^[15] L. Isaeva, G. Barbalinardo, D. Donadio, and S. Baroni, Modeling heat transport in crystals and glasses from a unified lattice-dynamical approach, Nat. Commun. 10, 3853 (2019).

^[16] A. Fiorentino and S. Baroni, From Green-Kubo to the full Boltzmann kinetic approach to heat transport in crystals and glasses, Phys. Rev. B 107, 054311 (2023).

^[17] M. Simoncelli, N. Marzari, and F. Mauri, Unified theory of thermal transport in crystals and glasses, Nat. Phys. 15, 809 (2019).

^[18] M. Simoncelli, N. Marzari, and F. Mauri, Wigner formulation of thermal transport in solids, Phys. Rev. X 12, 041011 (2022).

- [19] G. Caldarelli, M. Simoncelli, N. Marzari, F. Mauri, and L. Benfatto, Many-body Green's function approach to lattice thermal transport, Phys. Rev. B 106, 024312 (2022).
- [20] A. Fiorentino, P. Pegolo, and S. Baroni, Hydrodynamic finitesize scaling of the thermal conductivity in glasses, npj Comput. Mater. 9, 157 (2023).
- [21] A. F. Ioffe and A. R. Regel, in *Progresses in Semiconductors*, edited by A. F. Gibson (Heywood, London, 1960), Vol. 4, p. 237.
- [22] C. Ganter and W. Schirmacher, Rayleigh scattering, long-time tails, and the harmonic spectrum of topologically disordered systems, Phys. Rev. B **82**, 094205 (2010).
- [23] H. Mizuno, G. Ruocco, and S. Mossa, Sound damping in glasses: Interplay between anharmonicities and elastic heterogeneities, Phys. Rev. B 101, 174206 (2020).
- [24] A. Griffin, Brillouin light scattering from crystals in the hydrodynamic region, Rev. Mod. Phys. **40**, 167 (1968).
- [25] M. Baggioli and A. Zaccone, Theory of sound attenuation in amorphous solids from nonaffine motions, J. Phys.: Condens. Matter 34, 215401 (2022).
- [26] P. B. Allen and J. Kelner, Evolution of a vibrational wave packet on a disordered chain, Am. J. Phys. 66, 497 (1998).
- [27] G. Baldi, V. M. Giordano, and G. Monaco, Elastic anomalies at terahertz frequencies and excess density of vibrational states in silica glass, Phys. Rev. B 83, 174203 (2011).
- [28] M. G. Izzo, G. Ruocco, and S. Cazzato, The mixing of polarizations in the acoustic excitations of disordered media with local isotropy, Front. Phys. 6, 108 (2018).
- [29] M. G. Izzo, B. Wehinger, S. Cazzato, A. Matic, C. Masciovecchio, A. Gessini, and G. Ruocco, Rayleigh scattering and disorder-induced mixing of polarizations in amorphous solids at the nanoscale: 1-octyl-3-methylimidazolium chloride glass, Phys. Rev. B 102, 214309 (2020).
- [30] J. Garg, N. Bonini, B. Kozinsky, and N. Marzari, Role of disorder and anharmonicity in the thermal conductivity of silicon-germanium alloys: A first-principles study, Phys. Rev. Lett. 106, 045901 (2011).
- [31] G. Mahan, Effect of atomic isotopes on phonon modes, Phys. Rev. B **100**, 024307 (2019).
- [32] D. G. Cahill, M. Katiyar, and J. R. Abelson, Thermal conductivity of a-Si:H thin films, Phys. Rev. B 50, 6077 (1994).
- [33] A. Matthiessen and M. von Bose, On the influence of temperature on the electric conducting power of metals, Philos. Trans. R. Soc. **152**, 1 (1862).
- [34] J. M. Ziman, *Electrons and Phonons: The Theory of Transport Phenomena in Solids* (Oxford University Press, New York, 2001).
- [35] A. P. Thompson, H. M. Aktulga, R. Berger, D. S. Bolintineanu, W. M. Brown, P. S. Crozier, P. J. in 't Veld, A. Kohlmeyer, S. G. Moore, T. D. Nguyen, R. Shan, M. J. Stevens, J. Tranchida, C. Trott, and S. J. Plimpton, LAMMPS - a flexible simulation tool for particle-based materials modeling at the atomic, meso, and continuum scales, Comput. Phys. Commun. 271, 108171 (2022).
- [36] G. Barbalinardo, Z. Chen, N. W. Lundgren, and D. Donadio, Efficient anharmonic lattice dynamics calculations of thermal transport in crystalline and disordered solids, J. Appl. Phys. 128, 135104 (2020).
- [37] C. Tomaras, B. Schmid, and W. Schirmacher, Anharmonic elasticity theory for sound attenuation in disordered solids

- with fluctuating elastic constants, Phys. Rev. B **81**, 104206 (2010).
- [38] R. Haydock, *The Recursive Solution of the Schrödinger Equation* (Academic, New York, 1980), pp. 215–294.
- [39] N. Vast and S. Baroni, Effects of isotopic disorder on the Raman spectra of crystals: Theory and *ab initio* calculations for diamond and germanium, Phys. Rev. B 61, 9387 (2000).
- [40] G. H. Golub and C. F. Van Loan, *Matrix Computations* (Johns Hopkins University Press, Baltimore, MD, 2013).
- [41] E. Swartz and R. Pohl, Thermal resistance at interfaces, Appl. Phys. Lett. 51, 2200 (1987).
- [42] S.-M. Lee and D. G. Cahill, Heat transport in thin dielectric films, J. Appl. Phys. 81, 2590 (1997).
- [43] B. L. Zink, R. Pietri, and F. Hellman, Thermal conductivity and specific heat of thin-film amorphous silicon, Phys. Rev. Lett. 96, 055902 (2006).
- [44] H.-S. Yang, D. G. Cahill, X. Liu, J. L. Feldman, R. S. Crandall, B. A. Sperling, and J. R. Abelson, Anomalously high thermal conductivity of amorphous Si deposited by hotwire chemical vapor deposition, Phys. Rev. B 81, 104203 (2010).
- [45] X. Liu, J. L. Feldman, D. G. Cahill, R. S. Crandall, N. Bernstein, D. M. Photiadis, M. J. Mehl, and D. A. Papaconstantopoulos, High thermal conductivity of a hydrogenated amorphous silicon film, Phys. Rev. Lett. 102, 035901 (2009).
- [46] J. L. Braun, C. H. Baker, A. Giri, M. Elahi, K. Artyushkova, T. E. Beechem, P. M. Norris, Z. C. Leseman, J. T. Gaskins, and P. E. Hopkins, Size effects on the thermal conductivity of amorphous silicon thin films, Phys. Rev. B 93, 140201(R) (2016).
- [47] P. G. Klemens, The thermal conductivity of dielectric solids at low temperatures (theoretical), Proc. R. Soc. London A 208, 108 (1951).
- [48] L. Berthier and G. Biroli, Theoretical perspective on the glass transition and amorphous materials, Rev. Mod. Phys. 83, 587 (2011)
- [49] J. Jäckle, On the glass transition and the residual entropy of glasses, Philos. Mag. B 44, 533 (1981).
- [50] P. G. Debenedetti and F. H. Stillinger, Supercooled liquids and the glass transition, Nature (London) 410, 259 (2001).
- [51] L. Talirz, S. Kumbhar, E. Passaro, A. V. Yakutovich, V. Granata, F. Gargiulo, M. Borelli, M. Uhrin, S. P. Huber, S. Zoupanos et al., Materials cloud, a platform for open computational science, Sci. Data 7, 299 (2020).
- [52] A. Fiorentino, E. Drigo, S. Baroni, and P. Pegolo, Unearthing the foundational role of anharmonicity in heat transport in glasses, Materials Cloud Archive 2024, 77 (2024).
- [53] A. Fiorentino, P. Pegolo, and E. Drigo, hydro_glasses, https://github.com/afiorent/hydro_glasses.git.
- [54] P. Vashishta, R. K. Kalia, J. P. Rino, and I. Ebbsjö, Interaction potential for SiO₂: A molecular-dynamics study of structural correlations, Phys. Rev. B **41**, 12197 (1990).
- [55] L. Ercole, A. Marcolongo, and S. Baroni, Accurate thermal conductivities from optimally short molecular dynamics simulations, Sci. Rep. 7, 15835 (2017).
- [56] L. Ercole, *Ab Initio* Simulation of heat transport in silica glass, Ph.D. thesis, SISSA, 2018.

- [57] J. P. Rino, I. Ebbsjö, P. S. Branicio, R. K. Kalia, A. Nakano, F. Shimojo, and P. Vashishta, Short- and intermediate-range structural correlations in amorphous silicon carbide: A molecular dynamics study, Phys. Rev. B 70, 045207 (2004).
- [58] P. Vashishta, R. K. Kalia, A. Nakano, and J. P. Rino, Interaction potential for silicon carbide: A molecular dynamics study of elastic constants and vibrational density of states for crystalline and amorphous silicon carbide, J. Appl. Phys. 101, 103515 (2007).
- [59] J. Tersoff, Empirical interatomic potential for silicon with improved elastic properties, Phys. Rev. B **38**, 9902 (1988).
- [60] V. L. Deringer, N. Bernstein, A. P. Bartók, M. J. Cliffe, R. N. Kerber, L. E. Marbella, C. P. Grey, S. R. Elliott, and G. Csányi, Realistic atomistic structure of amorphous silicon from machine-learning-driven molecular dynamics, J. Phys. Chem. Lett. 9, 2879 (2018).
- [61] C. Paige, Accuracy and effectiveness of the Lanczos algorithm for the symmetric eigenproblem, Linear Algebra Appl. **34**, 235 (1980).